

DATASHEET

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER CNY17-X Series CNY17F-X Series







Features:

• Current transfer ratios in selected narrow range groups

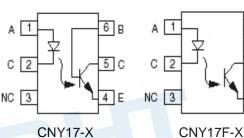
CNY17-1, CNY17F-1: 40-80% CNY17-2, CNY17F-2: 63-125%

CNY17-3, CNY17F-3: 100-200%

CNY17-4, CNY17F-4:160-320%

- High isolation voltage between input and output (Viso = 5000 Vrms)
- Creepage distance > 7.6 mm
- Operating temperature up to +110°C
- The CNY17F-X series offers no external base connection for minimum noise susceptibility
- Compact dual-in-line package
- •The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

Schematic



CNY17-X

Pin Configuration

- 1. Anode
- 2. Cathode
- 3. No Connection
- 4. Emitter
- 5. Collector
- 6. Base

Pin Configuration

Schematic

6 NC

5 C

- 1. Anode
- 2. Cathode
- 3. No Connection
- 4. Emitter
- 5. Collector
- 6. No Connection

Description

The CNY17-X and CNY17F-X series of devices each consist of an infrared emitting diode optically coupled to a phototransistor.

They are packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs



Absolute Maximum Ratings (Ta=25℃)

	Parameter	Symbol	Rating	Unit
	Forward current	I _F	60	mA
	Peak forward current (t = 10µs)	I _{FM}	1	А
Input	Reverse voltage	V _R	6	V
	Power dissipation (T _A = 25°C)	D	100	mW
	Derating factor (above 100°C)	P _D —	3.8	mW/°C
Output	Collector-Emitter voltage	V _{CEO}	80	V
	Collector-Base voltage*1	V _{CBO}	80	V
	Emitter-Collector voltage	V _{ECO}	7	V
	Emitter-Base voltage	V _{EBO}	7	V
	Power dissipation (T _A = 25°C)	D	150	mW
	Derating factor (above 100°C)	Pc —	9.0	mW/°C
Total Power Dissipation		Ртот	200	mW
Isolation voltage *2		V _{ISO}	5000	V rms
Operating Temperature		T _{OPR}	-55 to 110	°C
Storage Temperature		T _{STG}	-55 to 125	°C
Soldering temperature *3		T _{SOL}	260	°C

Notes:

^{*1} Only for CNY17-X series.

^{*2} AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together.

^{*3} For 10 seconds.



Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	V _F	-	-	1.65	V	I _F = 60mA
Reverse current	I_R	-	-	10	μΑ	$V_R = 6V$
Input capacitance	C_in	-	18	-	pF	V = 0, f = 1MHz

Output

Parameter		Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Base dark current	CNY17-X only	ГСВО	-	-	20	nA	V _{CB} = 10V, I _F = 0mA
Collector-Emitter dark current		I _{CEO}		-	50	nA	V _{CE} = 10V, IF=0mA
Collector-Emitter breakdown voltage		BV _{CEO}	80	-	-	V	$I_C = 1mA$, $I_F = 0mA$
Collector-Base breakdown voltage	CNY17-X only	ВУсво	80	11		V	$I_C = 0.1 \text{mA},$ $I_F = 0 \text{mA}$
Emitter-Collector breakdown voltage		BV _{ECO}	7	11.0	-	V	$I_E = 0.1 \text{mA},$ $I_F = 0 \text{mA}$
Collector-Emitter capacitance		CCE		8	-	pF	VCE = 0V, f =1MHz

^{*} Typical values at T_a = 25°C



Transfer Characteristics

Pa	arameter	Symbol	Min	Тур.	Max.	Unit	Condition	
	CNY17-1 CNY17F-1	— CTR - — -	40	-	80	%		
Current Transfer	CNY17-2 CNY17F-2		63	-	125		$I_F = 10 \text{mA}$, $V_{CE} = 5 \text{V}$	
Ratio	CNY17-3 CNY17F-3		100	-	200			
	CNY17-4 CNY17F-4		160	-	320			
	CNY17-1 CNY17F-1		13	-	-	%		
Current Transfer	CNY17-2 CNY17F-2	— CTR - — -	22	-	-		$I_F = 1 \text{mA}$, $V_{CE} = 5 \text{V}$	
Ratio	CNY17-3 CNY17F-3		34	-	-			
	CNY17-4 CNY17F-4		56	-	-			
Collector-Emitter saturation voltage		V _{CE(sat)}	-	-	0.3	V	$I_F = 10 \text{mA}$, $I_C = 2.5 \text{mA}$	
Isolation resistance		R _{IO}	1011	-	-	Ω	$V_{IO} = 500Vdc$	
Input-outpu	Input-output capacitance		-	0.5		pF	$V_{IO} = 0$, $f = 1MHz$	
Turn-on tim	Turn-on time		-	10	12			
Turn-off time		T_{off}	39-1	9	12		$V_{CC} = 10V$,	
Rise time		T _r	7.1	6	10		I_C = 2mA, R_L = 100 Ω See Fig. 11	
Fall time		T _f	-	8	10	μs		
Rise time		Tr	-	2	10		$V_{CC} = 5V, I_F = 10mA,$	
Fall time		T_f	-	3	10		$R_L = 75\Omega$, See Fig. 11	

^{*} Typical values at T_a = 25°C



Typical Electro-Optical Characteristics Curves

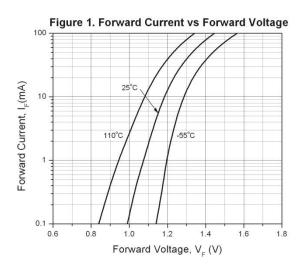
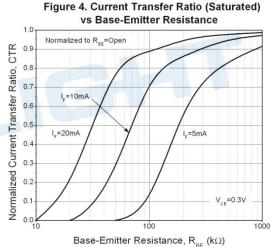
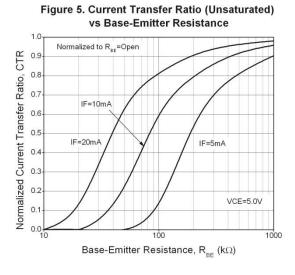


Figure 2. Current Tranfer Ratio vs Forward Current Normalized Current Transfer Ratio, CTR 1.0 0.8 0.6 V_{ce}=5 V 0.2 Ta=25°C Normalized to I_e=10 mA 0.0 Forward Current, I (mA)

Figure 3. Current Tranfer Ratio vs **Ambient Temperature** Normalized Current Transfer Ratio, CTR I_=20 mA I_e=10 mA I_F=2 mA 0.8 0.0 -40 40 60 100 Ambient Temperature, Ta (°C)





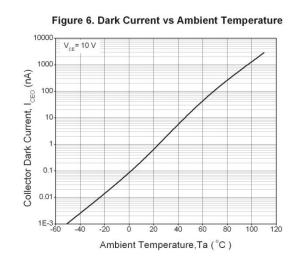


Figure 4. Current Transfer Ratio (Saturated)

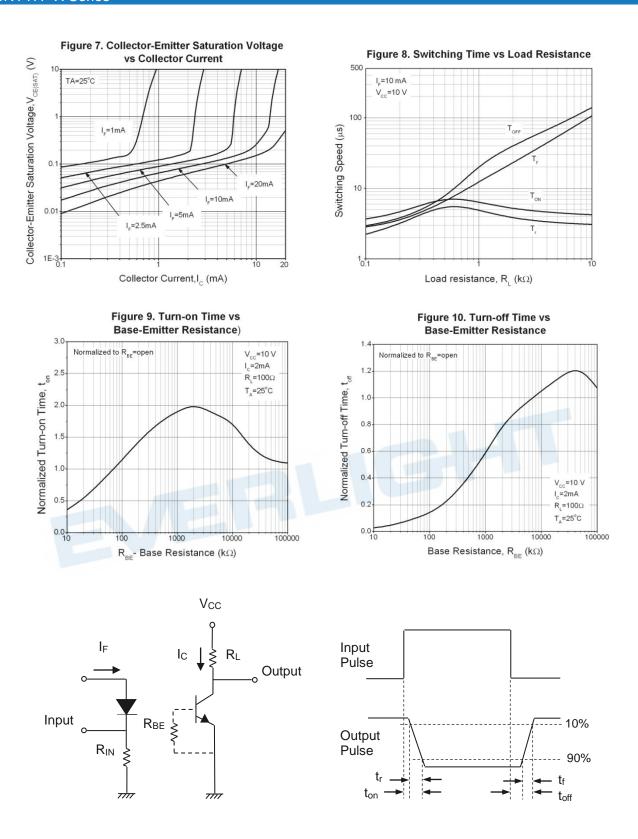


Figure 11. Switching Time Test Circuit & Waveforms



Order Information

Part Number

cny17-xy(z)-v cny17F-xy(z)-v

Note

X = Part no. (1, 2, 3 or 4)

Y = Lead form option (S, S1, M or none)

Z = Tape and reel option (TA, TB or none).

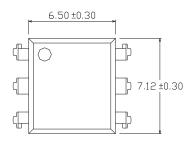
V = VDE (optional)

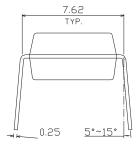
Option	Description	Packing quantity
None	Standard DIP-6	65 units per tube
М	Wide lead bend (0.4 inch spacing)	65 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel

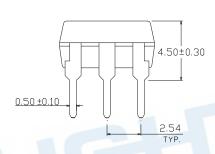


Package Dimension (Dimensions in mm)

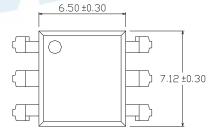
Standard DIP Type

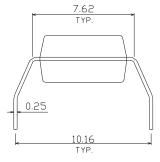


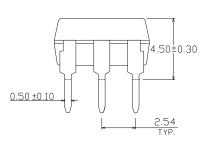




Option M Type

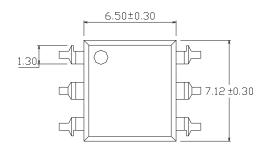


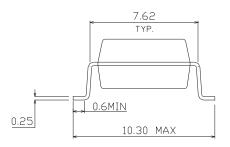


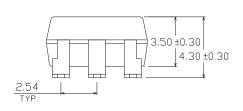




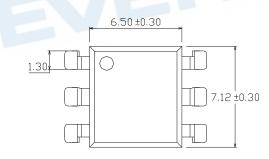
Option S Type

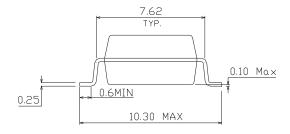


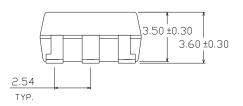




Option S1 Type

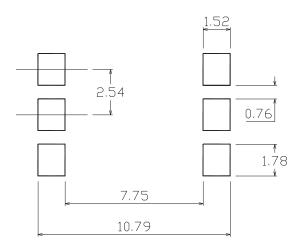




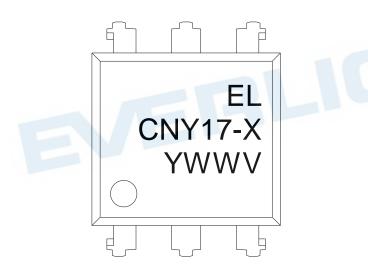




Recommended pad layout for surface mount leadform



Device Marking



Notes

EL denotes Everlight

CNY17-X denotes Device Number (X: 1, 2, 3 or 4)

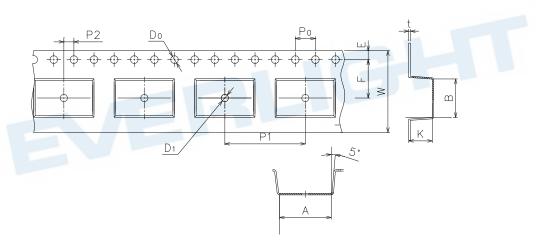
Y denotes 1 digit Year code WW denotes 2 digit Week code V denotes VDE (optional) Direction of feed from reel

Direction of feed from reel

Tape & Reel Packing Specifications

Option TA Option TB

Tape dimensions



Dimension No.	Α	В	Do	D1	E	F
Dimension (mm)	10.8±0.1	7.5±0.1	1.5±0.1	1.5+0.1/-0	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	w	К
Dimension (mm)	4.0±0.15	12±0.1	2.0±0.1	0.35±0.03	16.0±0.2	4.5±0.1

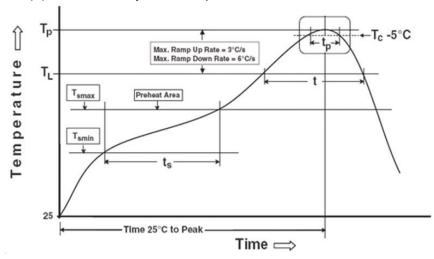


Reference: IPC/JEDEC J-STD-020D

Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Preheat

Temperature min (T_{smin}) 150 °C Temperature max (T_{smax}) 200 °C

Time $(T_{smin} \text{ to } T_{smax})$ (t_s) 60-120 seconds Average ramp-up rate $(T_{smax} \text{ to } T_p)$ 3 °C/second max

Other

Liquidus Temperature (T_L) 217 °C Time above Liquidus Temperature (t_L) 60-100 sec

Peak Temperature (T_P) 260°C

Time within 5 °C of Actual Peak Temperature: T_P - 5°C 30 s

Ramp- Down Rate from Peak Temperature 6°C /second max.

Time 25°C to peak temperature 8 minutes max.

Reflow times 3 times



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